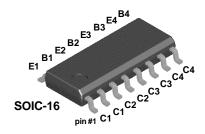


MMPQ2907



PNP General Purpose Amplifier

This device is designed for use as a general purpose amplifier and switch requiring collector currents to 500 mA. Sourced from Process 63.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| V_{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{CBO} | Collector-Base Voltage | 60 | V |
| V_{EBO} | Emitter-Base Voltage | 5.0 | V |
| I _C | Collector Current - Continuous | 600 | mA |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

TA = 25°C unless otherwise noted

| Symbol | Characteristic | Max | Units |
|-----------------|--|--------------|----------------------|
| | | MMPQ2907 | |
| P _D | Total Device Dissipation Derate above 25°C | 1,000 8.0 | mW mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient Effective 4 Die Each Die | 125 240 | °C/W °C/W °C/W |

^{*}Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

^{**}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

PNP General Purpose Amplifier

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

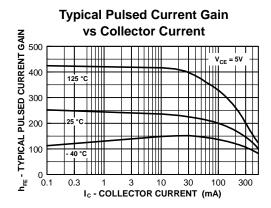
| Symbol | Parameter | Test Conditions | Min | Max | Units |
|----------------------|--------------------------------------|--------------------------------|-----|-----|-------|
| OFFICIAL | | | | | |
| OFF CHAR | RACTERISTICS | | | | |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage* | $I_C = 10 \text{ mA}, I_B = 0$ | 40 | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 60 | | V |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 5.0 | | V |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 30 V | | 50 | nA |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 30 V | | 50 | nA |

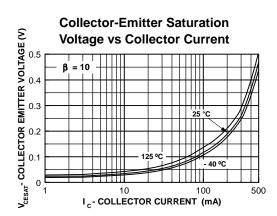
ON CHARACTERISTICS

| h _{FE} | DC Current Gain | I _C = 10 mA, V _{CE} = 10 V | 75 | | |
|----------------------|---------------------------------|---|-----|-----|---|
| | | $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}^*$ | 100 | 300 | |
| | | $I_C = 300 \text{ mA}, V_{CE} = 10 \text{ V}$ | 30 | | |
| | | $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}^*$ | 50 | | |
| V _{CE(sat)} | Collector-Emitter Saturation | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.4 | V |
| | Voltage* | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 1.6 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}^*$ | | 1.3 | V |
| | | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 2.6 | V |

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

Typical Characteristics





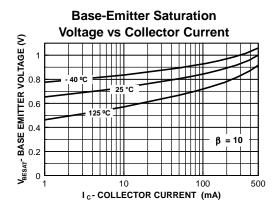
Spice Model

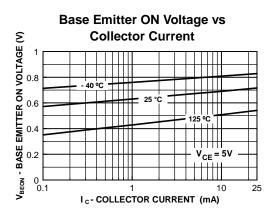
 $PNP \ (Is=650.6E-18 \ Xti=3 \ Eg=1.11 \ Vaf=115.7 \ Bf=231.7 \ Ne=1.829 \ Is=54.81f \ Ikf=1.079 \ Xtb=1.5 \ Br=3.563 \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=.715 \ Cjc=14.76p \ Mjc=.5383 \ Vjc=.75 \ Fc=.5 \ Cje=19.82p \ Mje=.3357 \ Vje=.75 \ Tr=111.3n \ Tf=603.7p \ Itf=.65 \ Vtf=5 \ Xtf=1.7 \ Rb=10)$

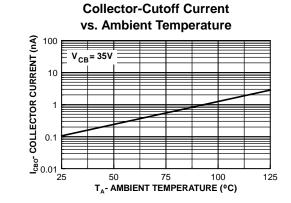
PNP General Purpose Amplifier

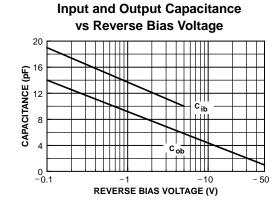
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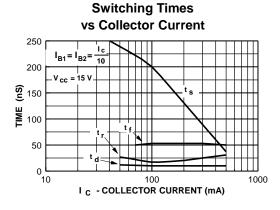
Typical Characteristics (continued)

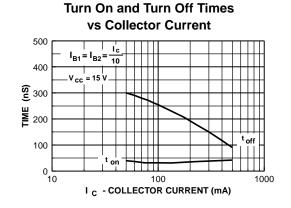








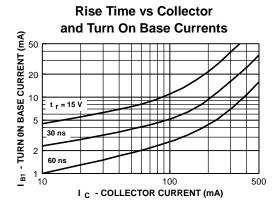


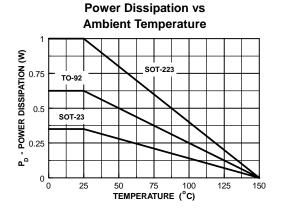


PNP General Purpose Amplifier

(continued)

Typical Characteristics (continued)





Test Circuits

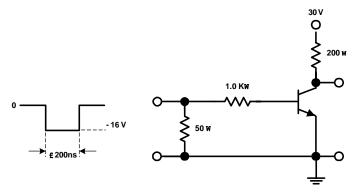


FIGURE 1: Saturated Turn-On Switching Time Test Circuit

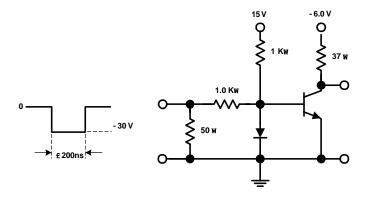


FIGURE 2: Saturated Turn-Off Switching Time Test Circuit

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